



Future Normal in Semiconductor

[TP] 포스터세션

2025-2-13(목), 09:00-18:30

A. Interconnect & Package 분과

TP-001	<p>Optimization of Fly Cutting Process for Cu/Polyimide Hybrid Bonding</p> <p>Suin Jang¹, Junyoung Choi¹, Dongmyeong Lee¹, Hoogwan Lee², and Sarah Eunkyung Kim¹</p> <p>¹Department of Semiconductor Engineering, Seoul National University of Science and Technology, ²Department of Electrical and Information Engineering, Seoul National University of Science and Technology</p>
TP-002	<p>Study of Low Temperature Cu-to-Cu Bonding using Reducing Plasma Pretreatment</p> <p>Dongmyeong Lee¹, Hoogwan Lee², Junyoung Choi¹, Suin Jang¹, and Sarah Eunkyung Kim¹</p> <p>¹Department of Semiconductor Engineering, Seoul National University of Science and Technology, ²Department of Electrical and Information Engineering, Seoul National University of Science and Technology</p>
TP-003	<p>Characterization of PVD SiCN Thin Films for Chip Stacking</p> <p>Junyoung Choi¹, Suin Jang¹, Dongmyeong Lee¹, Hoogwan Lee², and Sarah Eunkyung Kim¹</p> <p>¹Department of Semiconductor Engineering, Seoul National University of Science and Technology, ²Department of Electrical and Information Engineering, Seoul National University of Science and Technology</p>
TP-004	<p>EExperimental Data Management Platform for Data-Driven Investigation of Interconnect Materials</p> <p>Joonho Bang¹, Beomjun Kim², and Dongwoo Lee¹</p> <p>¹School of Mechanical Engineering, Sungkyunkwan University, ²Department of Semiconductor Convergence Engineering, Sungkyunkwan University</p>
TP-005	<p>The mechanical effect of soft pad on copper chemical mechanical polishing</p> <p>Pengzhan Liu and Taesung Kim</p> <p>Sungkyunkwan University</p>



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TP-006	<p>Study of Cu Dishing After Cu CMP Based on Pad Layouts and Its Impact on Hybrid Bonding</p> <p>Sunjae Kim¹, Kangmin Seo¹, Hoogwan Lee¹, Sangwoo Park², and Sarah Eunkyung Kim²</p> <p>¹Department of Electrical and Information Engineering, Seoul National University of Science and Technology, ²Department of Semiconductor Engineering, Seoul National University of Science and Technology</p>
TP-007	<p>3D-Printed Antenna-in-Package Substrates with Quasi-Coaxial Through-Vias for 5G-Advanced Applications</p> <p>Nahyeon Kim¹, Haksoon Jung², Yurim Choi², Yongwoo Lee², Yunsik Park³, Seungyeon Koh⁴, Hyeok Kim⁴, and Jimin Kwon^{1,2}</p> <p>¹Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ²Department of Electrical Engineering, UNIST, ³ICT Device & Packaging Research Center, KETI, ⁴School of Electrical and Computer Engineering, University of Seoul</p>
TP-008	<p>Inkjet-Printed Photoresist Films for Panel-Level Packaging Using Glass Interposers</p> <p>Yurim Choi¹, Yongwoo Lee¹, Haksoon Jung¹, Nahyeon Kim², and Jimin Kwon^{1,2}</p> <p>¹Department of Electrical Engineering, UNIST, ²Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>
TP-009	<p>Enhancing Semiconductor Package Molding Set-up Efficiency Through Machine Learning</p> <p>Hae Chan Rho^{1,2} and Jae Woo Lee²</p> <p>¹Package Development, SK Hynix, ²Department of Semiconductor Convergence Engineering, Korea University</p>
TP-010	<p>Study on Ti-based intermetallic compounds as a new interconnect material</p> <p>Seung-Jun Na¹ and Hoo-Jeong Lee^{1,2}</p> <p>¹Department of Smart Fab. Technology, Sungkyunkwan University, ²School of Advanced Materials Science and Engineering, Sungkyunkwan University</p>
TP-011	<p>Plasma Surface Treatment Technique to Overcome the Trade-Off Between Sheet Resistance and Transmittance in Ultra-Thin Cu Based Flexible Transparent Electrodes</p> <p>Jae Woo Park¹, Jeong Eun Chae², and Doo Ho Choi¹</p> <p>¹Gachon University, ²Test Analysis and Evaluation Center, GERI</p>



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TP-012	<p>Optimizing the Ag-TiO₂ Interface with Ar⁺ Ion Bombardment to reach the Optimal Haacke Figure of Merit</p> <p>Chankyong Lee¹, Jeong Eun Chae², and Dooho Choi¹</p> <p>¹Gachon University, ²Test Analysis and Evaluation Center, GERI</p>
TP-013	<p>Time-Constant Spectrum Extracted by Utilizing the Subspace Barzilai and Borwei Non-Negative Least Square Algorithm for Thermal Transient Analysis</p> <p>Joosun Yun¹, Byongjin Ma², Guesuk Lee², Tae-Hee Jung², Dong-Soo Shin³, Youngbeom Kim¹, and Hyundon Jung¹</p> <p>¹EtaMax Co., Ltd., ²KETI, ³Hanyang University ERICA</p>
TP-014	<p>Development of New High-speed Inline SAT Machine Focusing on Improvement HBM Capability & Application of AI solutions</p> <p>Han Nu Ri Park¹ and Sang Yup Lee²</p> <p>¹SK hynix Inc., ²H. Milton Stewart School of Industrial and Systems Engineering, Georgia Institute of Technology</p>
TP-015	<p>Computational Exploration of Binary Alloys for Advanced Interconnects</p> <p>Gyungho Maeng¹, Subeen Lim¹, Bonggeun Shong², and Yeonghun Lee¹</p> <p>¹Department of Electronics Engineering, Incheon National University, ²Department of Chemical Engineering, Hongik University</p>
TP-016	<p>A Comprehensive Analysis of Cu Dishing and Pad Design in Cu-Cu Hybrid Bonding</p> <p>Yeon Ju Kim and Jong Kyung Park</p> <p>Department of Semiconductor Engineering, Seoul National University of Science and Technology</p>
TP-017	<p>Enhanced Contact Resistance Measurement in Cu Hybrid Bonding for Advanced Heterogeneous Integration</p> <p>Kyoung Min Shin and Jong Kyung Park</p> <p>Seoul National University of Science and Technology</p>
TP-018	<p>Improving Power Efficiency in Semiconductor Interconnects through Development and Methodology Proposal</p> <p>Tae-Yeong Hong, Dong-Yun Sung, and Seul-Ki Hong</p> <p>Department of Semiconductor Engineering, Seoul National University of Science and Technology</p>



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TP-019	<p>칩렛 시스템 구현을 위한 저비용 패키지 설계 기법 개발 Chungju Kim, Tai Sik Yang, and Yong Seok Kang LG Electronics Inc.</p>
TP-020	<p>공정열처리 유무에 따른 ALD Ru/ZnO 구조의 박막응력과 계면접착에너지 간의 상관관계 분석 김민진¹, 공혜영¹, 이수연¹, 정대윤¹, 김가희¹, 손예슬², 김민우², 김수현^{2,3}, 박영배¹ ¹국립안동대학교 청정·에너지소재기술연구센터, ²울산과학기술원 반도체 소재·부품 대학원, ³울산과학기술원 신소재공학과</p>
TP-021	<p>Deep Neural Networks (DNN) Supported Thermal Management for Advanced VLSI Packaging Jun Ho Lee¹, Jae Gyu Kim¹, Seong Jin Kim¹, Ju Hwan Kim², Woong Seo², Jae Yong Song¹, and Byoung Don Kong¹ ¹POSTECH, ²SAPEON Korea Inc.</p>
TP-022	<p>Hardmask-Film CMP Slurry containing Sulfate Radical Oxidant for High Quality Surface Roughness and High Polishing-Rate Min-ji Kim, Yun-heub Song, and Jae-Gun Park ¹Department of Electronic Engineering, Hanyang University</p>
TP-023	<p>Gaussian Fitting Volume Approximation for PR Coating Compensation Kyo Mun Ku, Mi Jin Kim, MD Saiful Islam, Hyo Yung Kim, Jae Hong Shim, and Ki Hyun Kim Tech University of Korea</p>
TP-024	<p>Enhancement of TID Resistance through Aluminum Shielding Je Won Park and Myoung Jin Lee Department of Intelligent Electronics and Computer Engineering, Chonnam National University</p>
TP-025	<p>Topological Semimetals for Highly Scaled Interconnect Subeen Lim, Gyungho Maeng, and Yeonghun Lee Department of Electronics Engineering, Incheon National University</p>
TP-026	<p>A Study on the Effects of Wire Diameter and Die Tilt on the Thermal and Electrical Performance of Si-IGBT Based on DOE Dong-Hyeon Kim^{1,2} and Sung-Uk Zhang^{1,2} ¹Digital Twin Laboratory, ²Center for Brain Busan ²¹ Plus Program</p>



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TP-027	<p>Thin Film Growth of Topological Semi-metal for Future Electronic Device Sehun Oh and Hyeon-Jin Shin Department of Semiconductor Engineering, School of Electrical Engineering and Computer Science, GIST</p>
TP-028	<p>Time-dependent Growth and Microstructural Characterization of through-hole via Fill Varying Plating Additives Eun-Bi Lee¹, So-Yeon Lee¹, Seung-Yong Lee², and Kyung-A Won² ¹Kumoh National Institute of Technology, ²YLG Innotek</p>
TP-029	<p>Process Automation for Evaluating Reliability of AI Accelerator Min Seo Song¹, Seung Hyeon Cha¹, Sangyul Ha¹, and Jihoon Kang² ¹Myong Ji University, ²PKG Development, SK Hynix</p>
TP-030	<p>Electrochemical Growth of Micrometer-scale Cu Single Crystals Compatible with Microscale Patterns Giho Jeong¹, Kyung-Ho Park² and Jae Yong Song^{1,3} ¹Graduate school of semiconductor technology, POSTECH, ²Advanced Packaging TF, KANC, ³Dept of Semiconductor Engineering and Dept of MSE, POSTECH</p>
TP-031	<p>Resistivity Scaling Model for CNT-embedded Metal Interconnects Huiyun Jung, Seunggyu Hwang, Bogeun Son, Jaewon Park and Hongsik Park School of Electronic and Electrical Engineering, Kyungpook National University</p>
TP-032	<p>Investigation of BEOL Metal Height Variation with Pattern Density Siin Kim, Suhyeon Cha, Seon Gyo Jang, Joon Nyung Lee, Hyejun Jin, Jeong Hoon Ahn, and Jong-Ho Lee Foundry business, Samsung Electronics</p>
TP-033	<p>Reliability of fatigue deformation for flexible Cu interconnect varying interfacial adhesion Jeong A Heo, Jun Hyeok Hyun, and So-Yeon Lee Kumoh National Institute of Technology</p>
TP-034	<p>Enhancement of IR Thermography for Semiconductor Packages Using Pixel-Level Emissivity Correction Seongjin Kim¹, Min Gyu Jo², and Jae Yong Song^{1,3,4} ¹Department of Materials Science and Engineering, POSTECH, ²Department of Materials Science and Engineering, Korea University, ³Department of Semiconductor Engineering, POSTECH, ⁴Graduate school of semiconductor technology, POSTECH</p>



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TP-035	<p>Additive-free Electrochemical Synthesis of Single-crystal Copper Nanowires for BEOL Interconnection</p> <p>Jae Wook LEE¹, Jae Yong SONG^{1,2}</p> <p>¹Graduate School of Semiconductor Technology, POSTECH, ²Department of Semiconductor Engineering and Department of Materials Science and Engineering, POSTECH</p>
TP-036	<p>CVT Growth of Molybdenum Phosphide Thin Films for BEOL Applications</p> <p>Yeji Shin¹, Jae Yong Song^{1,2,3}</p> <p>¹Department of Graduate School of Semiconductor Technology, POSTECH, ²Department of Semiconductor Engineering, POSTECH, ³Department of Materials Science and Engineering, POSTECH</p>
TP-037	<p>Dependence of Diffusion Barrier Characteristics on Post-Treatment Methods for SiCN Films Deposited in Plasma-Enhanced Chemical Vapor Deposition Using 1-(Trimethylsilyl)pyrrolidine Precursor</p> <p>Kyubeom Bae, Jaeyeon Kim, Chanyong Seo, Jeongbeom Choi, Namwuk Baek, and Donggeun Jung</p> <p>Department of Physics, Sungkyunkwan University</p>
TP-038	<p>Dielectric Properties of Low-k Films Deposited at 300 °C in Plasma Enhanced Chemical Vapor Deposition System Using Tris(trimethylsiloxy)silane Precursor</p> <p>Jaeyeon Kim, Kyubeom Bae, Chanyong Seo, Namwuk Baek, Jeongbeom Choi, and Donggeun Jung</p> <p>Department of Physics, Sungkyunkwan University</p>
TP-039	<p>Analysis of the substrate effect on electrical characteristics of channels for 2.5D packaging using glass interposers</p> <p>Donghyun Uhm¹, Junu Choi¹, Kyuho Sung¹, Jaeyoung Choi¹, and Jaemyung Lim^{1,2}</p> <p>¹Department of Electronic Engineering, Hanyang University, ²Department of Nano Semiconductor Engineering, Hanyang University</p>
TP-040	<p>Improving Joint Properties of Cu Pillar Bumps using Ni Diffusion Barrier Layer and IPL Soldering</p> <p>Eun-ChaeNoh, Eun-SuJang, and Jeong-WonYoon</p> <p>¹Department of AdvancedMaterialsEngineering, Chungbuk National University</p>



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TP-041	<p>Highly Robust Sintered Silver Pressureless Bonding Using Self-Heating of PMMA in Silver Paste</p> <p>Moses Gu¹, Hyun Jin Nam², Se Hoon Park², and Sung-Hoon Choa</p> <p>¹Seoul National University of Science and Technology, Intelligent Semiconductor Engineering Department, ²KETI, ICT Device and Packing Center</p>
TP-042	<p>차량용 전장 부품 연결을 위한 FPCB Ni-Sn-Cu 접합부의 전기적 기계적 신뢰성 연구</p> <p>고명수¹, 이용규¹, 김지정², 김병준¹</p> <p>¹한국공학대학교 신소재공학과, ²현대자동차, 전기전자재료개발팀</p>
TP-043	<p>반도체 패키징용 SR/EMC 계면의 고온 및 고습 조건에서 접착 에너지 변화 연구</p> <p>마지수¹, 김원빈², 고영관³, 주영창², 김병준¹</p> <p>¹한국공학대학교, 신소재공학과, ²서울대학교 재료공학부, ³삼성전자</p>
TP-044	<p>전력반도체 패키징을 위한 Ag 및 Cu@Ag 소결 접합 특성 연구</p> <p>Mi So Won, Dajung Kim, and Chulmin Oh</p> <p>Electronic Convergence Materials & Device Research Center, KETI</p>
TP-045	<p>Effect of Surface Finish on Solder Joint Reliability in Electronic Packaging</p> <p>Jeeyeon Park¹, Chulmin Oh¹ , and Jeong-Won Yoon²</p> <p>¹KETI, ²Chungbuk National University</p>
TP-046	<p>저온 경화형 Glass Package Substrate용 Resin Coated Copper 개발</p> <p>김선우^{1,2}, 김유빈², 남현진², 류제인², 박성준¹, 박세훈²</p> <p>¹성균관대학교, 화학공학과, ²한국전자기술연구원, ICT 디바이스패키징연구센터</p>
TP-047	<p>Optimization of die and clip attach process for double-sided bonding of Power module</p> <p>Dajung Kim¹, Yun Hwa Choi² , Hoseob Park², and Chulmin Oh¹</p> <p>¹KETI, ²JMJ Korea Co. LTD</p>
TP-048	<p>Enhancing Structure Functions for Accurate Thermal Characterization and Monitoring of Semiconductor Packages: Sampling Optimization and Geometric Analysis</p> <p>Wonbin Song¹, Guesuk Lee², and Byeng D. Youn^{1,3}</p> <p>¹Seoul National University., ²Korea Electronics Technology Institute, ³One Predict Inc.</p>



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<p>TP-049</p>	<p>Development of Stretchable Low-Dielectric Film Using Hydrophobic PDMS with Porous Silica and Surfactant Moses Gu¹, Hyun Jin Nam², Se Hoon Park², and Sung-Hoon Choa¹ ¹Seoul National University of Science and Technology, Intelligent Semiconductor Engineering Department, ²KETI, ICT Device and Packing Center</p>
<p>TP-050</p>	<p>Through-InP-Via (TIV)-embedded 3D Metal Interconnection Technology between InP and SiC Substrates for RF Application Jonghyun Song^{1,2}, Hyoungho Ko², and Jongwon Lee² ¹NNFC, ²Chungnam National University</p>
<p>TP-051</p>	<p>A Study on Signal Integrity in Hybrid Bonding with Misalignment for Stacked Die Chan-Woong Park¹ and Kee-Won Kwon² ¹Department of Electrical and Computer Engineering, Sungkyunkwan University, ²Department of Semiconductor Systems Engineering, Sungkyunkwan University</p>
<p>TP-052</p>	<p>Evaluation of SiO₂ Bonding Strength using Various Plasma Gases for Hybrid Bonding Injoo Kim¹, Siye Lee¹, Jinho Jang², Minji Kang², Hyein Jin³, Soohyun Ko², and Sungdong Kim² ¹Department of Mechanical Design and Robot Engineering, Seoul National University of Science and Technology, ²Department of Mechanical System Design Engineering, Seoul National University of Science and Technology, ³Department of Manufacturing Systems and Design Engineering, Seoul National University of Science and Technology</p>
<p>TP-053</p>	<p>Surface Treatment Methods for Cu-Cu Bonding in Cu/SiO₂ Hybrid Bonding Siye Lee¹, Injoo Kim¹, Jinho Jang², Minji Kang², Hyein Jin³, Sunghwan Joo⁴, and Sungdong Kim² ¹Department of Mechanical Design and Robot Engineering, Seoul National University of Science and Technology, ²Department of Mechanical System Design Engineering, Seoul National University of Science and Technology, ³Department of Manufacturing Systems and</p>
<p>TP-054</p>	<p>Precise Evaluation of Electrical Contact on Ultra-thin Silicided Semiconductors Using Bridge-contact Resistance (BCR) method Seunggyu Hwang, Bogeun Son, Huiyun Jung, and Hongsik Park School of Electronic and Electrical Engineering, Kyungpook National University</p>



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TP-055	<p>Measurement and Analysis of Through Glass Via (TGV) for High-Speed ??Interface 2.5D/3D Package</p> <p>Suin Chae and Je-In Yu KETI</p>
TP-056	<p>Dry Etching Technology for Sub-10 ?m Vertical Via Formation in Build-Up Films for Advanced Semiconductor Packaging</p> <p>Sunbum Kim¹, Gyulee Kim¹, Kyoungyeon Min², Dugkyu Han¹, Young Ju Han³, Soonoh Jeong³, Mooseong Kim³, and Changhwan Choi^{1,2}</p> <p>¹Division of Materials Science and Engineering, Hanyang University, ²Department of Semiconductor Engineering, Hanyang University, ³LG Innotek</p>
TP-057	<p>Signal Characteristics of Coplanar Waveguide Structure Redistribution Layer on PSPI Substate</p> <p>Dugkyu Han¹, Sunbum Kim¹, Gyulee Kim¹, Kyoungyeon Min², and Changhwan Choi^{1,2}</p> <p>¹Division of Materials Science and Engineering, Hanyang University, ²Division of Semiconductor Engineering, Hanyang University</p>
TP-058	<p>Development of a Dry Desmear Process for High-Performance Packaging and Analysis of Smear Removal Efficiency</p> <p>Kyoungyeon Min¹, Sunbum Kim², Gyulee Kim², Dugkyu Han², Young Ju Han³, Soonoh Jeong³, Mooseong Kim³, and Changhwan Choi^{1,2}</p> <p>¹Department of Semiconductor Engineering, Hanyang University, ²Division of Materials Science and Engineering, Hanyang University, ³LG Innotek</p>
TP-059	<p>Effect of Plasma Parameters on the Properties of Low-k SiCOH Films Grown by Plasma-Enhanced Chemical Vapor Deposition Using Dimethyldimethoxysilane</p> <p>Seong-Bin Park^{1,2}, Jinseok Choi¹, H. J. Yeom¹, Gwang-Seok Chae¹, Kwan-Yong Kim¹, Wonchul Kee³, Hyo-Chang Lee^{4,5}, Hyun-Dam Jeong³, and Jung Hyung Kim¹</p> <p>¹KRISS, ²Department of Mechanical Engineering, Yonsei University, ³Department of Chemistry, Chonnam National University, ⁴School of Electronics and Information Engineering, Korea Aerospace University, ⁵Department of Semiconductor Science, Engineering and Technology, Korea Aerospace University</p>

B. Patterning (Lithography & Etch Technology)



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TP-060	<p>Hybrid Multilayer Extreme Ultraviolet Resist with Vertical Molecular Wire Structure for Exceptionally Low Line Edge Roughness Jaehyuk Lee, Hyeonseok Ji, Chaerim Kim, and Myung Mo Sung Department of Chemistry, Hanyang University</p>
TP-061	<p>Advanced Dry Development of EUV Photoresist by Organic Precursor Namseon Jang, Hyeonseok Ji, Jaehyuk Lee, Hyejeong Oh, Juyeong Lee, and Myung Mo Sung Department of Chemistry, Hanyang University</p>
TP-062	<p>Heptafluoroisopropyl trifluoromethyl ketone을 이용한 SiO₂와 Si₃N₄의 plasma 식각 김민욱^{1,2}, 김창구^{1,2} ¹Department of Chemical Engineering, Ajou University, ²Department of Energy Systems Research, Ajou University</p>
TP-063	<p>Observation of Cross-Sectional Photoresist Patterns Using FIB Seohyeon Lee¹, Ye Jin Ku², Gayoung Kim², Jin-Kyun Lee², and Byung Jun Jung¹ ¹University of Seoul, ²Inha University</p>
TP-064	<p>Mask 3D effect의 완화가 가능한 high-NA EUV 마스크용 광학상수 영역 분석 연구 이승호^{1,2}, 정동민^{1,2}, 김연수^{1,2}, 이태호², 안진호^{1,2} ¹한양대학교 신소재공학과, ²Center for Hyperscale, Hyperfunction, Heterogeneous Integration Pioneering Semiconductor Technology</p>
TP-065	<p>Gapless Stencil Lithography Utilizing PMMA Protective Layer for Facile Fabrication of 2D Materials Electronics Devices Jaemin Myoung^{1,2}, Taehyeon Kim^{1,2}, Seunghun Lee³, Jeonghwan Kim³, Taesung Kim², and Jihun Mun¹ ¹Korea Research Institute of Standards and Science, ²Sungkyunkwan University, ³Hanbat National University</p>
TP-066	<p>Positive-tone Tin-Oxo Nanocluster Resists for Extreme UV Lithography exploiting Lewis Acid-Base Interaction Chemistry Gayoung Kim¹, Yejin Ku¹, Subin Jeon¹, Jin-Kyun Lee¹, Seohyun Lee², Byung Jun Jung², Sung-Il Lee³, Choonghan Ryu³, Kangho Park³, Yun Lim Jung³, Changyoung Jeong³, Jin Choi³ ¹Inha University, ²University of Seoul, ³Samsung Electronics Co., Ltd.,</p>



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<p>TP-067</p>	<p>Cyclic Etching Using Organic Gas/O₂ Mixture for Formation of 150 nm Co Line Patterns Ha Rin Song, Dae Han Won, Hong Ju Yang, and Chee Won Chung Department of Chemical Engineering, Inha University</p>
<p>TP-068</p>	<p>A Low-Power Compact-Area PMOS-based Two-Stage Operational Amplifier in a 180-nm CMOS Seungyun Phee, Eunjae Ko, Jimin Oh, Yujin Lee, Somi Park, Sunkyung Lee, Bobin Seo, and Sung Min Park Division of Electronic & Semiconductor Engineering, Ewha Womans University</p>
<p>TP-069</p>	<p>Effects of Electronegativity on Electron Energy Distribution Function and Ion Energy Distribution Function in Ar/O₂ Inductively Coupled Plasma Haneul Lee¹, Hwiwon Seo¹, Namjae Bae¹, Gon-Ho Kim¹, and Seolhye Park² ¹Seoul National University, ²Samsung Display</p>
<p>TP-070</p>	<p>Synthesis and Characterizations of a Novel Non-Alkyl Tin Oxo Cluster CNU-TOC-01(4C-C) and its Application to EUV Lithography Hyeok Yun¹, Jiyong Bang¹, Minyeob Kim¹, Hyun-Dam Jeong¹, Hyung-Bae Moon², Cheol-Min Kim², Hee-Seon Lee³, Kyuyoung Heo³, Siwoo Noh⁴, Geonhwa Kim⁴, Sangsul Lee⁴, and Ki-Jeong Kim⁴ ¹Chonnam National University, ²Chem Laboratory, ³KRICT, ⁴Pohang Accelerator Laboratory</p>
<p>TP-071</p>	<p>Investigation of the Effect of Electron Beam Irradiation on Dibenzyltin Diacetate Using Local Thin Film Analysis and Quantum Chemical Calculations Hyeok Yun, Hyun-Dam Jeong Chonnam National University</p>
<p>TP-072</p>	<p>Tapered Micro-hole Silicon Array Formed by Diffusion-limited Wet Etch Process for Robust and Highly-efficient Energy Devices Yebin Ahn, Soohyeok Park, Sangbeom Hong, Hyein Cho, Geonhwi Kim, Yejin Han, Inkyeong Park, Seongmin Lee, Jihwan Jeong, Taewan Kim, Gayeong Lee, and Han-Don Um Kangwon National University</p>
<p>TP-073</p>	<p>Advanced Anisotropic Etching Process using Ozone for Fabrication of Silicon Nano Structures Hyein Cho, Yebin Ahn, Sang Beom Hong, Soohyeok Park, Yejin Han, Geonhwi Kim, Inkyeong Park, Seongmin lee, Taewan Kim, Jihwan Jeong, Gayeong Lee, and Han-Don</p>



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	Um Kangwon National University
TP-074	Extreme Ultraviolet Lighting Source based on the C-beam Irradiation Technique with Silicon Target Iksu Kim, Umesh Balaso Apugade, and Kyu Chang Park Kyung Hee University
TP-075	Evaluation of Stability of C- Beam Irradiation Generated EUV Light Umesh Balaso Apugade, Iksu Kim, and Kyu Chang Park Kyung Hee University
TP-076	Impact of Exposure Dose on Micro-patterns of OLED Layers Eun Yeong Soh ¹ , Seohyeon Lee ¹ , Dongjin Shin ¹ , Byung Jun Jung ¹ , Gayoung Kim ² , Jin-Kyun Lee ² , Sangmin Yoon ² , and Myungwoong Kim ² ¹ University of Seoul, ² Inha University
TP-077	Enhanced vertical etching of silicon by controlled metal catalysts of metal-assisted chemical etch method Yejin Han, Yebin Ahn, Hyein Cho, Sangbeom Hong, Geonhwi Kim, Soohyeok Park, Inkyeong Park, Seongmin Lee, Taewan Kim, Jihwan Jeong, Gayeong Lee, and Han-don Um Kangwon National University
TP-078	Ultrafine Pattern Transfer Based on Sequential Infiltration Synthesis Il-Suk Kang, Yeon-Wha Oh, Sanghee Jung, Jungchul Song, Huijae Cho, and Se-Hun Kwon ¹ National Nanofab Center, KAIST, ² Pusan National University
TP-079	Optimizing LiNbO₃ Waveguides: ICP-RIE and Post-Cleaning for Enhanced Performance Namhoon Kim ¹ , Heon-jin Choi ² , and Donghee Park ¹ ¹ Center for Quantum technology, KIST, ² Department of Material Science and Engineering, Yonsei University



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TP-080	<p>Simulating Internal Resist Behavior and Its Impact on EUV Lithography Pattern Performance</p> <p>Hyunseok Kim¹, Jihun Ahn¹, and Su-Mi Hur^{1,2}</p> <p>¹Department of Polymer Engineering, Graduate School, Chonnam National University (CNU), ²School of Polymer Science and Engineering, Chonnam National University (CNU)</p>
M. RF and Wireless Design	
TP-081	<p>Design of Radio-Frequency Receiver with Wireless Power Transfer</p> <p>Taeyoung Kim, Jongho Lee, Gyungtae Ryu, Hoyeon Sin, and Ickhyun Song</p> <p>Hanyang University</p>
TP-082	<p>A TID and SEE Radiation-Hardened-by-Design Receiver</p> <p>Taeyoung Kim, Jongho Lee, Gyungtae Ryu, Hoyeon Sin, and Ickhyun Song</p> <p>Hanyang University</p>
TP-083	<p>A CMOS-based Optoelectronic Receiver IC for LiDAR Sensors</p> <p>Yunji Song^{1,2} and Sung Min Park^{1,2}</p> <p>¹Division of Electronic & Semiconductor Engineering, Ewha Womans University, ²Graduate Program in Smart Factory, Ewha Womans University</p>
TP-084	<p>An Optoelectronic Inverter Transimpedance Amplifier in 180-nm CMOS</p> <p>Bobin Seo^{1,2}, Sunkyung Lee^{1,2}, Somi Park^{1,2}, and Sung-Min Park^{1,2}</p> <p>¹Division of Electronic & Semiconductor Engineering, Ewha Womans University, ²Graduate Program in Smart Factory, Ewha Womans University</p>
TP-085	<p>A Current-Mode VCSEL Driver for Short-Range LiDAR Sensors</p> <p>Juntong Li^{1,2} and Sung Min Park^{1,2}</p> <p>¹Division of Electronic & Semiconductor Engineering, Ewha Womans University, ²Graduate Program in Smart Factory, Ewha Womans University</p>
TP-086	<p>A CMOS Active-Feedback Transimpedance Amplifier for LiDAR Sensors</p> <p>Somi Park^{1,2}, Sunkyung Lee^{1,2}, Bobin Seo^{1,2}, and Sung-Min Park^{1,2}</p> <p>¹Division of Electronic and Semiconductor Engineering, Ewha Womans University, ²Graduate Program in Smart Factory, Ewha Womans University</p>



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TP-087	<p>커플드 라인 부하 회로를 활용한 11 dB 백오프 3-Way 도허티 전력 증폭기</p> <p>김상엽¹, 임서균¹, 전형진^{1,2}, 양영구^{1,2}</p> <p>¹성균관대학교 전자전기컴퓨터공학과, ²para-PA Inc</p>
TP-088	<p>결합선로를 사용한 간소화된 광대역 동작 도허티 전력증폭기</p> <p>주윤희¹, 전형진^{1,2}, 양영구^{1,2}</p> <p>¹성균관대학교 전자전기컴퓨터공학과, ²para-PA Inc</p>
TP-089	<p>Out-phased current combining을 이용한 2.8-4.3 GHz 대역 도허티 전력증폭기 설계</p> <p>안민석¹, 최영찬¹, 임서균¹, 양영구^{1,2}</p> <p>¹성균관대학교 전자전기컴퓨터공학과, ²para-PA Inc.</p>
TP-090	<p>Design of Doherty Power Amplifier with Output Power Back-off of 7.23 dB</p> <p>Ren Liu¹ and Youngoo Yang^{1,2}</p> <p>¹Department of Electrical and Computer Engineering, Sungkyunkwan University, ²para-PA Inc.</p>
TP-091	<p>0.9 dB 이하의 잡음 지수를 갖는 X 밴드 저잡음 증폭기 설계</p> <p>임서균¹, 김상엽¹, 양영구^{1,2}</p> <p>성균관대학교 전기전자컴퓨터공학과</p>
TP-092	<p>단일 병렬 다이오드를 이용한 35 GHz 정류기 설계</p> <p>문규현¹, 빈수현¹, 양영구^{1,2}</p> <p>¹성균관대학교 정보통신대학 전자전기컴퓨터공학과, ²para-PA Inc</p>
TP-093	<p>비대칭 전력 분배기를 이용한 도허티 전력 증폭기 설계</p> <p>김민수¹, 이윤정¹, 주윤희¹, 양영구^{1,2}</p> <p>¹성균관대학교 전자전기컴퓨터공학과, ²para_PA</p>
TP-094	<p>RF Front-End Application 을 위한 SOI RF 스위치를 대체 할 DTI 공정이 적용된 HRS RF 스위치 (HRS RF Switch with DTI as an Alternative to SOI RF Switch for RF Front-End Applications)</p> <p>전태현, 유창현, 김희수, 김용은, 김기준, 김대일, 김경록, 정진효</p> <p>DB HiTek</p>

S. Chip Design Contest



Future Normal in Semiconductor

TP-095	Fan-Out Buffer with Automatic Skew Control Yun-Hyok Choi, Jae-hyun Park, and Byung-Sung Kim RF Microelectronic Design Lab., Sungkyunkwan University
TP-096	Asymmetric SPDT Switch with High Isolation and Low Insertion Loss Jae Eun Lee ¹ , Choul Young Kim ¹ , and Gwang Hyeon Jeong ² ¹ Department of Engineering, Chungnam National University, ² Department of Semiconductor System Engineering, Hanbat National University
TP-097	A Reconfigurable Artifact-Tolerant Analog Front-End IC for Bidirectional Neural SoCs Soonseong Hong ^{1,2} , Hyojun Yoo ^{1,2} , Bosung Park ² , Daeyeong Jeon ² , and Hyouk Kyu Cha ² ¹ Samsung Electronics Co., Ltd., ² Seoul National University of Science and Technology
TP-098	A Multi-Mode CMOS Image Sensor for Cognitive Imaging Taehyoung Kim, Kiwon Seo, Jongho Jung, and Gunhee Han School of Integrated Technology, Yonsei University
TP-099	Built-in Self Repair Circuit for Improving Reliability of 3D Stacked Memory Donghyun Han, Heetae Kim, Jongho Park, Hyojoon Yun, Sunghoon Kim, Seung Ho Shin, Duyeon Won, and Sungho Kang Yonsei University
TP-100	Energy-Efficient Neural Processing Unit for Object Detection Seongmin Ki, Hyunmin Kim, Gwanghwi Seo, Yeonggeon Kim, and Sungju Ryu Sogang University
TP-101	ReRAM-based AI Accelerator with Ternary Input and Septenary Weight having On-Chip Write-Verify Dong Hyuk Ahn ¹ , Seo Yoon Lee, Ho Jin Lee ² , Young Hyun Lee ² , and Kee Won Kwon ¹ ¹ Department of Semiconductor and Display Engineering, Sungkyunkwan University, ² Department of Electrical and Computer Engineering, Sungkyunkwan University
TP-102	An Input-Buffer Embedding Dual-Residue Pipelined SAR ADC with Non-binary Capacitive Interpolation Raymond Mabilangan, Seung-Yong Lim, and Seung-Tak Ryu School of Electrical Engineering, KAIST



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TP-103	Impedance Measurement IC for Wireless Sensor Readout Su-Hwan Kim and Kyeongha Kwon KAIST
TP-104	A 10-bit Column-Driver IC with High-Speed DAC with Feed-Forward Paths for OLED Display Haesang Park, June hee Lee, and Byong-Deok Choi Department of Electronic Engineering, Hanyang University
TP-105	Injection Locked Frequency Division-by-4 with High Harmonic Rejection Ratio Akram Muhamad Rafli, Muhammad Fakhri Mauludin, and Jusung Kim Hanbat National University
TP-106	A Highly Sensitive D-band Detector using 180-nm CMOS Process for Millimeter-Wave Imaging System Ha-Neul Lee, Jae-Hyun Lee, and Jong-Ryul Yang Konkuk University
TP-107	High-Efficiency Digital LDO Leveraging Single VCO and Dual Frequency Gain Control for Optimal Current Performance SongI Cheon, YoonSang Lee, JunYoung Choi, Hyunsu Jang, Chanbin Hwang, SeungMyeong Yu, Jongchan An, and JunYoung Song Department of Electronics Engineering, Incheon National University
TP-108	Active Common-Mode Termination Circuit for Automotive Link Yong-Hui Yun and Sang-Gug Lee KAIST
TP-109	HBC Rx to Obtain in vivo Bio-Signals and Endoskeleton Pressure Sensor Signals Hyunyeop Lee, Yunchul Chung, Dongyoon Lee, and Minkyu Je KAIST
TP-110	A Multi-mode NS-SAR ADC with MOM-capacitor for CMOS Image Sensor Kiwon Seo, Taehyoung Kim, Jongho Jung, and Gunhee Han School of Integrated Technology, Yonsei University



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TP-111	<p>Fully Integrated On-Chip EIS System ByeongHo Hwang, YunChae Lee, UiKyoung Lee, JiHan Shin, and KyeongHa Kwon KAIST</p>
TP-112	<p>A V-band Digital-controlled Variable Gain Amplifier with 6-bit Tuning Range and 0.5-dB Resolution in 28nm CMOS Technology In Cheol Yoo, Dong Ouk Cho, and Chul Woo Byeon Department of Electronic and Electrical Engineering, Dankook University</p>
TP-113	<p>A Sub-50-fs RMS Jitter, 103.5-GHz Fundamental-Sampling PLL With an Extended Loop Bandwidth Jooeun Bang¹, Jaeho Kim², Seohee Jung², and Jaehyook Choi² ¹KAIST, ²Seoul National University</p>
TP-114	<p>High PSR and Fast Slew Rate Capacitor-less LDO Using Multi-Paths Bong Su Kim, Gyu Won Jeon, Gwang Myeong An, Hyang Hee Park, Jin Soo Bae, Myeong Ju Park, Min Gyun Kim, and Jun Young Song Department of Electronics Engineering, Incheon National University</p>
TP-115	<p>Fully Dynamic Discrete-Time Delta-Sigma Modulator with Digital Noise Coupling Younghun Moon and Seung Tak Ryu School of Electrical Engineering, KAIST</p>
TP-116	<p>A V-Band Low-Loss Compact Power Divider/Combiner with Coupling Inductor in 28nm CMOS Technology Yeon Soo Lim, Taek Min Park, and Chul Woo Byeon Department of Electronic and Electrical Engineering, Dankook University</p>
TP-117	<p>Low-Power Word-Line Voltage Generation for NAND Flash Memory Hyunsik Jeong¹, Donghwan Kim², and SeongHwan Cho² ¹SK Hynix, ²KAIST</p>
TP-118	<p>Low-Power Fast-Settling Duty-Cycled PPG Readout using a Zero-Volt Regulator Pangi Park and SeongHwan Cho KAIST</p>



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TP-119	<p>전류 재사용 구조 기반 9.2-18.0 GHz 광대역 저잡음 증폭기</p> <p>이남경, 김지수, 오준택 숭실대학교 지능형반도체학과</p>
TP-120	<p>A 20-MS/s Flash ADC with Foreground Calibration for Process Time Reduction</p> <p>Jeong Wook Han and Byoung-ho Kim Hanyang University</p>
TP-121	<p>A Low-Jitter and Compact-Area Fractional-N Digital PLL with Fast Multi-Variable Calibration</p> <p>Seheon Jang¹, Munjae Chae¹, Hangi Park^{1,2}, Chanwoong Hwang^{1,2}, and Jaehyoun Choi¹ ¹Seoul National University, ²KAIST</p>
TP-122	<p>A High-Performance Boost Converter for Wearable TEG with High Efficient MPPT and Self-Startup in 28 nm CMOS Process</p> <p>Jung Hyun Moon, Arooba Shafique, and Jong Wook Lee Department of Electronic Engineering, Kyung Hee University</p>
TP-123	<p>Gate Driver for Silicon Carbide MOSFET with Adaptive Soft Turnoff Technique</p> <p>Youngseok Kwak¹, Seungjik Lee², Jinman Myoung¹, Geonwoo Park¹, and Ilku Nam¹ ¹Department of Electric Engineering, Pusan National University, ²Onsemi</p>
TP-124	<p>Dynamic Resource Management in Reconfigurable SoC for Multi-Tenancy Support</p> <p>Sohyeon Kim and Ji-Hoon Kim Ewha Womans University</p>
TP-125	<p>Torsion-Assisted Via-Anchor Nanoelectromechanical Memory Switches</p> <p>Jin Wook Lee, Geun Tae Park, and Woo Young Choi Seoul National University and Inter-university Semiconductor Research Center</p>
TP-126	<p>CMOS Digitally Driven Pixel Circuit for Modular Display</p> <p>Hyung-Min Song, Min-Seo Kim, and Byong-Deok Choi Department of Electronic Engineering, Hanyang University</p>



Future Normal in Semiconductor

TP-127	<p>Leakage-Current-Suppressed Pixel Circuits for Micro-LED on Silicon San Kim¹, Joo-Sun Lee², and Byong-Deok Choi^{1,2} ¹Department of Display Science and Engineering, Hanyang University, ²Department of Electronic Engineering, Hanyang University</p>
TP-128	<p>5080-PPI OLED on Silicon Pixel Circuit for Wide Data Range Hyeon-Jun Shin, Hyeon-Ji Lee, and Byong-Deok Choi Department of Electronic Engineering, Hanyang University</p>
TP-129	<p>An 8-bit 20-MSPS SAR ADC with Delay-driven Calibration with Asynchronous Clock Generator Jiwon Lee and Byoungho Kim Hanyang University</p>
TP-130	<p>Efficient CIM Macro Controller Logic Sukhyun Choi¹, Hyunmyung Oh², and Jae-Joon Kim¹ ¹Seoul National University, ²POSTECH</p>
TP-131	<p>Advancing Vision Technology: Design and Fabrication of a High-Performance Retina Chip using 180nm BCDMOS Technology Md Turiqul Islam, Seunghyeok Choi, Abdey Munaf, Porika Nandini, Hyun-woo Jin, Gaurav Mehra, and Hanjung Song Department of Nanoscience and Engineering, Gimhae</p>
TP-132	<p>A 0.25V, 1MHz Clocking Hybrid Flip-Flop for Near Threshold Computing Seokhan Jeong and Junghyup Lee DGIST</p>
TP-133	<p>Observation of Electrode-Gap Narrowing in Nanoelectromechanical (NEM) Memory Switches Seung Hun Baek, Geun Tae Park, Myeong Su Shin, and Woo Young Choi Seoul National University and Inter-University Semiconductor Research Center</p>
TP-134	<p>Design of polysilicon grating couplers in FD-SOI platform Hyunmin Shin, Youngjae Jeong, Pradono Rizki Arif, and Kyoungsik Yu KAIST</p>



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TP-135	<p>Reduction of t_{RCD} through Parasitic Component Isolation in 1T-1C DRAM Ju Hong Min¹, Ji Hun Kang¹, and Jang Hyun Kim^{1,2} ¹Department of Intelligence Semiconductor Engineering, Ajou University, ²Department of Electronic Engineering, Ajou University</p>
TP-136	<p>A 8T SRAM-based Digital Compute-In-Memory Macro with In-SRAM Approximation Scheme Huiwon Kim and Jongsun Park Department of Electrical Engineering, Korea University</p>
TP-137	<p>Area-Efficient Partially-Parallel FWHT Processor for OFDM/CDMA communication 황용택, 황지우, 구교덕, 유호영 충남대학교 전자공학과</p>
TP-138	<p>Diffrenciator-based Noise Injection SCA-resistant LDO with 15 dB Noise Magnitude Control Ayeon Gwon, Yeseul Song, and Junwon Jeong Sookmyung Women's University</p>
TP-139	<p>SPAD Arrays for direct Time-of-Flight (dToF) LiDAR 채종혁, 조영민, 범진욱 Sogang University</p>
TP-140	<p>A 3.2 GHz Ring Oscillator Based Charge Pump PLL Achieveing Lower Than -110 dBcHz in-band Phase Noise Seunghoon YI¹, Yoochang Kim¹, Hee-Cheol Joo¹, and Young-Ha Hwang^{1,2} ¹Department of Intelligent Semiconductors, Soongsil University, ²School of Electronic Engineering, Soongsil University</p>
TP-141	<p>A 64-channel Time-multiplexed Neural Recording IC with Dual Positive Feedback Loop Z_{IN}-Boosting Christopher Santos, Dong-Hwi Choi, and Minkyu Je KAIST</p>
TP-142	<p>A High-Resolution Linear-Exponential Incremental ADC Minkyu Yang, Changjoo Park, Joeeun Kim, Jeongmyeong Kim, Dalta Imam Maulana, and Wanyeong Jung KAIST</p>



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<p>TP-143</p>	<p>Output-Capacitorless Low-Dropout Regulator with Dynamic Current Source Ji-Sun Lee and Jong-Seok Kim Department of Electrical and Electronic Engineering, Hanyang University ERICA</p>
<p>TP-144</p>	<p>A Compact Power-On Reset Circuit with Brown-Out Detection for DRAM Modules Yoochang Kim¹ and Young-Ha Hwang^{1,2} ¹Department of Intelligent Semiconductors, Soongsil University, ²School of Electronic Engineering, Soongsil University</p>
<p>TP-145</p>	<p>An Output-Capacitor-Free, Transient-Enhanced FVF LDO Supporting Up to 70-mA Load at 0.1-V Dropout Hee-Cheol Joo¹ and Young-Ha Hwang^{1,2} ¹Department of Intelligent Semiconductors, Soongsil University, ²School of Electronic Engineering, Soongsil University</p>
<p>TP-146</p>	<p>Ka-Band Bi-Directional Vector-Sum Phase Shifter Using Linearity Improved X-Type Variable Attenuator Jaehui Jung and Byung-wook Min Yonsei University</p>
<p>TP-147</p>	<p>Scalable Transformer Accelerator with Variable Systolic Array for Multiple Models Seok-Woo Chang and Dong-Sun Kim Sejong University</p>
<p>TP-148</p>	<p>Verification of Elementary Technology for nvSRAM Platform Woon-San Ko, Jun-Ho Byun, Do-Yeon Lee, So-Yeon Kwon, and Ga-Won Lee Chungnam National University</p>
<p>TP-149</p>	<p>외부 커패시터가 없는 이벤트 기반 비동기 방식의 99.99% 최대 전류 효율을 가지는 Digital LDO Ji-Hoon Song^{1,2}, Yeong-Hun Kim^{1,2}, Ho-Jin Kwark², and Kang-Yoon Lee^{1,2} ¹SKAIchips Co., Ltd., ²Department of Electrical and Computer Engineering, Sungkyunkwan University</p>



Future Normal in Semiconductor

TP-150	<p>Ka-Band Bi-directional 2-Way Active Power Divider with Reverse Bypass Mode for Phased Array Signal Distribution Networks</p> <p>Youngjoo Lee, Hyeonhak Lim, and Byung-Wook Min Yonsei University</p>
TP-151	<p>A Wide Dynamic Range $\Delta\Sigma$ Current-to-Digital Converter with a Truncation-Noise-Shaped Baseline-Servo-Loop in 0.18μm CMOS</p> <p>Taeryoung Seol, Minoo Lee, and Junghyup Lee DGIST</p>
TP-152	<p>A 1V-Supply Wide Input-Range 2nd-Order Noise-Shaping SAR-ADC with Enhanced Input Impedance in 0.18μm CMOS</p> <p>Geunha Kim, Jiho Kim, and Junghyup Lee DGIST</p>
TP-153	<p>A Switching Battery Charger with Ripple-Based Real-Time Built-In-Resistance Compensation for Fast-Charging</p> <p>Geuntae Park, Seongil Yeo, Chanjung Park, and Kunhee Cho Kyungpook National University</p>
TP-154	<p>High Accuracy Analog Spiking Neural Network with Offset Voltage Canceled Neuron Circuit</p> <p>Yun-Su Kim, Dong-Won Lee, Min-Woo Kim, Yu-Guan Kim, Won-Jo Lee, Jung-Hwan Hwang, and Byung-Do Yang School of Semiconductor Engineering, Chungbuk National University</p>
TP-155	<p>An Ultra-Compact and Energy-Efficient Synapse and LIF Neuron Circuit for On-chip Spiking Neural Networks</p> <p>Gaurav Mehra, Abdey Munaf, Hyeon Woo Jin, and Han Jung Song ¹Department of Nanoscience and Engineering, Center for Nano Manufacturing, Inje University</p>
TP-156	<p>A Dual-Output Hybrid Charger Providing Simultaneous Two-Cell Battery Charging and System Supply Voltage with Input Current Limiting Feature</p> <p>Chanjung Park, Seongil Yeo, Geuntae Park, and Kunhee Cho Kyungpook National University</p>
TP-157	<p>Area and Power Efficient Counter Mode DRBG Architecture through Feedback-Based AES Integration</p> <p>Van-Khanh Pham, Chi-Trung Ngo, Sang-Tran, Ji-Woo Choi, and Jong-Phil Hong Chungbuk National University</p>



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TP-158	A 1.7-pJ/bit 64Gb/s PAM-4 transmitter in 28nm CMOS with Tail-less current mode driver Jonghyeok Won and Jintae Kim Konkuk University
TP-159	Single-Inductor Multiple-Output DC-DC Converter Hohyun Kim, Donghyun Kim, Seoyeon Park, Heejin Lee, Jisoo Kim, Minseok Kim, Haechan Park, Jiho Jung, Minkwang Ji, Jooyun Oh, and Joongho Choi University of Seoul
TP-160	주입 잠금 오실레이터 기반 물리적 복제 불가능 함수의 설계 Kang-Min Kim and Min-Seong Choo Hanyang University
TP-161	A CI-C Asynchronous SAR ADC with Common-mode Level Shifting Seungjun Song and Hyungil Chae Konkuk University
TP-162	A High-Speed V-Band Distributed OOK Modulator in 65 nm CMOS Zubair Mehmood, Jingbo Zhang, and Munkyo Seo School of Electronic and Electrical Engineering, Sungkyunkwan University
TP-163	A High-Speed V-Band Distributed OOK Demodulator in 65 nm CMOS Zubair Mehmood, Atiq Ben Ahmed, and Munkyo Seo School of Electronic and Electrical Engineering, Sungkyunkwan University
TP-164	CMOS N-path Circulator and Blocker Tolerant Balun-Low Noise Amplifier with Time-Domain RF Self-Interference Cancellation Chaerin Park, Seungyeon Kim, and Kuduck Kwon Department of Electronics Engineering, Kangwon University
TP-165	Design of SSB mixer with improved Harmonic Rejection Hyun-Seok Jeong, SungHwan Park, Jun-Kyo Park, and Byung-Sung Kim RF Microelectronic Design Lab., Sungkyunkwan University



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TP-166	<p>A 128x128x4 CMOS Active Microelectrode Array System for EIS Hyunseo Shin, Jun-Seok Beom, and Nam-Seog Kim Chungbuk National University</p>
TP-167	<p>Analysis of Proton-Irradiation Effects on 28nm MOSFETs Jisung Im¹, Hansol Kim¹, Sung Yun Woo¹, Haesung Kim², Sung-Jin Choi², Dae Hwan Kim², Jong-Ho Bae², Yu-Mi Kim³, Dong Myong Kim^{2,4}, Young Jun Yoon⁵, and Kwanso Park⁶ ¹School of Electronic and Electrical Engineering, Kyungpook National University, ²School of the Electronic Engineering, Kookmin University, ³KAERI, Korea Atomic Energy Research Institute, ⁴Department of Advanced Technology, DGIST, ⁵Department of Electronic Engineering, Andong National University, ⁶Department of Systems Semiconductor Engineering, Yonsei University</p>
TP-168	<p>A Galvanically-Coupled Body-Channel-Communication Transmitter with Passive Charge Balancing for Implanatable Device Dong-Hwi Choi, Dongyoon Lee, Yunchul Chung¹, Hyunyeop Lee¹, and Minkyu Je¹ KAIST</p>
TP-170	<p>High-Performance 3D Object Detection Accelerator Using Sparse Pillar Mapping Minjae Lee, Dowon Kim, and Jungwook Choi Hanyang University</p>
TP-171	<p>Design of Refresh Prediction Circuits for DRAM Applications Byeongyu Kim, Sewoong Ahn, Eojin Kim, Yeongo Kim, and Young-Jae Min Department of Electric and Electronic Engineering, Halla University</p>
TP-172	<p>A Low-Area, High-Speed, and High-Uniformity 10b Source-Driver IC for OLED-on-Silicon Displays Junghwan Oh, Wiman Yoo, Dong-Kun Lee, and Jong-Seok Kim Department of Electrical and Electronic Engineering, Hanyang University ERICA</p>
TP-173	<p>A 28nm Reconfigurable and Memory-Efficient Digital Neuromorphic Processor ChangMin Ye¹, Choongseok Song¹, Yongwook Sim¹, and Doo Seok Jeong^{1,2} ¹Division of Materials Science and Engineering, Hanyang University, ²Department of Semiconductor Engineering, Hanyang University</p>



Future Normal in Semiconductor

TP-174	<p>24-43 GHz Down-Conversion Mixer and Dual-Band LO Buffer with Switchable Inductor for 5G New Radio FR2 Cellular Applications</p> <p>Yunji Seong, Heesu Lee, and Kuduck Kwon Department of Electronics Engineering, Kangwon National University</p>
TP-175	<p>Wide Input Range Readout Integrated Circuit for Efficient Signal Extraction in Gas Sensor Systems</p> <p>Jang Su Hyeon, Soon Kyu Kwon, and Hyeon June Kim ¹Seoul National University of Science and Technology</p>
TP-176	<p>Triple-stacked Distributed Amplifiers Using CMOS 28 nm process</p> <p>Hosung Kang, Seungyoon Han, and Jihoon Kim Kyonggi University</p>
TP-177	<p>Novel ADC Design for MRAM-Based PiM Systems: Enhancing Performance, Energy Efficiency, and Accuracy</p> <p>Seoyoung Lee, Donghyeon Yi, and Minkyu Je School of Electrical Engineering, KAIST</p>
TP-178	<p>A Current-Mode Denoising Autoencoder for On-Chip Learning with Weight-Specific Gradient Accumulation Storage</p> <p>Jeong-Min Woo, Hyungmin Kang, and Hyunwoo Son School of Electronic Engineering, Gyeongsang National University</p>
TP-179	<p>A Duty-Cycled Bandwidth and Power Scalable CTDSM for ExG Biopotential Recording</p> <p>Woo Yub Chun and Jung Hyup Lee DGIST</p>
TP-180	<p>An 8-Channel Low-Power Distributed Stimulation Chip for Electroceutical Application</p> <p>Joonyoung Lim, Chae-Eun Lee, Chieun Choi, Jong-hyun Park, Gwang-ho Choi, Seok-won Joo, and Yoon-Kyu Song Graduate School of Convergence Science and Technology, Seoul National University</p>
TP-181	<p>Module Designs of an Analog Adaptive Spike Detection System</p> <p>Joonyoung Lim, Chae-Eun Lee, Chieun Choi¹, Jong-hyun Park, Gwang-ho Choi, Seok-won Joo, and Yoon-Kyu Song Graduate School of Convergence Science and Technology, Seoul National University</p>



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TP-182	<p>Optimized ROIC Design with SNR Enhancement for SWIR Imaging Systems Dong-Yeon Lee, Min-Jun Park, and Hyeon-June Kim Seoul National University of Science and Technology</p>
TP-183	<p>Layout Pattern Optimization for Reducing Coupling Noise in Column-Parallel CMOS Image Sensors Hyeong-Min Park, Sang-Hyeon Kim, and Hyeon-June Kim Seoul National University of Science and Technology</p>
TP-184	<p>RF 에너지 하베스팅 시스템을 위한 100 nA의 대기 전류 및 고속 과도 응답 특성을 갖는 출력 커패시터 없는 LDO 레귤레이터 Jiho Jung¹, and Ickjin Kwon² Department of Electrical and Computer Engineering, Ajou University</p>

I. MEMS & Sensor Systems

TP-185	<p>Nonlinear and Bipolar Photoresponse Multifunctional Logic Gate Using p-Type Doped MAPbI₃ for 8 Logic Operations in a Single Device Dante Ahn^{1,2}, Minz Lee^{1,3}, and Yusin Pak¹ ¹Sensor System Research Center, KIST, ²KU-KIST Graduate School of Converging Science and Technology, Korea University, ³Department of Materials Science and Engineering, Korea University</p>
TP-186	<p>Enhancing the Resistive Switching Properties of Transparent HfO₂-Based Memristor Devices for Reliable Gasistor Applications Taegi Kim¹, Doowon Lee², and Hee-Dong Kim¹ ¹Department of Electrical Engineering and Convergence Engineering for Intelligent Drone, Sejong University, ²Division of Electrical, Electronic and Control Engineering, Kongju National University</p>
TP-187	<p>Heater for In-vehicle NO₂ Quality Monitoring System Ik-Geun Kwon¹, Doowon Lee², and Hee-Dong Kim¹ ¹Department of Electrical Engineering and Convergence Engineering for Intelligent Drone, Sejong University, ²Division of Electrical, Electronic and Control Engineering, Kongju National University</p>



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TP-188	<p>Photosynaptic Characteristics of IGZO Field-Effect Transistors with Different IGZO Sputtering Conditions</p> <p>Hojoon Jeong¹, Changyong Oh², and Bo Sung Kim¹</p> <p>¹Division of Display and Semiconductor Physics, Korea University, ²DRAM PA Team, Samsung Electronics Co., Ltd.</p>
TP-189	<p>Enhanced Response And Recovery Observed in CNTs Gas Sensors Using ZnO/HfO₂ Bilayer Memristor Heater</p> <p>Mohsin Ali¹, Doowon Lee², and Hee-Dong Kim¹</p> <p>¹Department of Semiconductor Systems Engineering, Convergence Engineering for Intelligent Drone, and Institute of Semiconductor and System IC, Sejong University, ²Division of Electrical, Electronic and Control Engineering, Kongju National University</p>
TP-190	<p>Self-Clocking True Random Number Generator with Enhanced Stochasticity in Polymer-Blended Perovskite</p> <p>Minz Lee^{1,2}, Yeon Kyung Lee¹, and Yusin Pak¹</p> <p>¹Sensor System Research Center, KIST, ²Department of Materials Science and Engineering, Korea University</p>
TP-191	<p>Advanced Humidity Resistance and Rapid Recovery in CNTs Gas Sensor via Filament Heater Integration</p> <p>Ibtisam Ahmad¹, Doowon Lee², and Hee-Dong Kim¹</p> <p>¹Department of Semiconductor Systems Engineering and Convergence Engineering for Intelligent Drone, Sejong University, ²Division of Electrical, Electronic and Control Engineering, Kongju National University</p>
TP-192	<p>Implementation of Bayesian Network and Bayesian Inference using Cu_{0.1}Te_{0.9}/HfO₂/Pt Threshold Switching Memristor</p> <p>In Kyung Baek^{1,2}, Soo Hyung Lee^{1,2}, Sunwoo Cheong^{1,2}, and Cheol Seong Hwang^{1,2}</p> <p>¹Department of Materials Science and Engineering, Seoul National University, ²Inter-University Semiconductor Research Center, Seoul National University</p>
TP-193	<p>16 x 16 Active Matrix Temperature Sensor Array Using IGZO Thin-Film Transistors</p> <p>Hyunsoo Kim¹, Hyerin Jo², Jaegoo Lee², and Hongseok Oh^{1,2}</p> <p>¹Department of Intelligent Semiconductor, Soongsil University, ²Department of Physics, Soongsil University</p>
TP-194	<p>High-Performance Dual-Gate Field Effect Transistor for Enhanced Cortisol Detection in Biosensor Platform</p> <p>Seong-Hwan Lim, Seung-Jin Lee, and Won-Ju Cho</p> <p>Department of Electronic Materials Engineering, Kwangwoon University</p>



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<p>TP-195</p>	<p>Reconfigurable Ion-Sensitive Field-Effect Transistors based CMOS-Compatible Biosensor Platform Seung-Hwa Choi, Tae-Hwan Hyun, and Won-Ju Cho Department of Electronic Materials Engineering, Kwangwoon University</p>
<p>TP-196</p>	<p>Effect of asymmetric air-gap on dual FET-type gas sensor considering thermoelectric effect Hunhee Shin, Jinwoo Park, Donghee Kim, Jaehyeon Kim, Kangwook Choi, and Jong-Ho Lee Department of Electrical and Computer Engineering and Inter-University Semiconductor Research Center (ISRC), Seoul National University</p>
<p>TP-197</p>	<p>Dynamic Reconfigurable pH-Sensing Device Based on Organic-Inorganic Hybrid MSQ Electric-Double Layer with CMOS Compatibility Tae-Gyu Hwang, Seung-Hyun Lee, and Won-Ju Cho Department of Electronic Materials Engineering, Kwangwoon University</p>
<p>TP-198</p>	<p>Reliable NO₂ Gas Identification Across Humidity Levels Using a Neuromorphic Olfactory System with p- and n-Type SnO_x gas Sensors Donghee Kim and Jong-Ho Lee Department of Electrical and Computer Engineering and ISRC, Seoul National University</p>
<p>TP-199</p>	<p>Polycrystalline Silicon-based Electrically Doped Fin Structure Programmable Photodiode for Convolution Neural Network Seungyeob Kim, Giuk Kim, Seonjae Park, Taeseung Jeong, and Sanghun Jeon School of Electrical Engineering, KAIST</p>
<p>TP-200</p>	<p>Vacancy Modulated Memristive Sensor for Risk-Level Detection Yujin Nam¹, June Soo Kim¹, Seung Deok Kim¹, Noah Jang¹, Hyunjun Kim¹, Da Ye Kim¹, Jinkyung Kim¹, Jin Park¹, Kihyun Kim¹, Seong Ho Kong¹, and Maeum Han² ¹School of Electronic and Electrical Engineering, Kyungpook National University, ²Institute of Semiconductor Fusion Technology, Kyungpook National University</p>
<p>TP-201</p>	<p>A Micro Ionic Wind Generator Using Plasma-on-chip Jisu Shin, Himchan Lee, and Youngmin Kim Hongik University</p>



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TP-202	<p>전극두께의 최적화를 통한 $Ag_2O/\beta-Ga_2O_3$ 이종접합 기반 DUV 광검출기 성능 향상</p> <p>오혜성, 김기환, 김지형, 김해찬, 신성민, 홍정수 가천대학교 IT 융합대학 전기공학과</p>
TP-203	<p>Enhanced Room-Temperature Gas Sensing of TiO_2 and Au Nanoparticles from Nanocomposite</p> <p>Jin Park¹, Jinkyung Kim¹, Kihyun Kim¹, Seong Ho Kong¹, June Soo Kim², Seung Deok Kim², Noah Jang², Hyunjun Kim², Da Ye Kim², Yujin Nam², and Maeum Han³ ¹Department of Semiconductor science, Kyungpook National University, ²School of Electronic and Electrical Engineering, Kyungpook National University, ³Institute of Semiconductor Fusion Technology, Kyungpook National University</p>
TP-204	<p>Freestanding Waveguide-Integrated Bolometer on Germanium-on-Insulator Platform for Mid-infrared on-Chip Gas Sensor</p> <p>Inki Kim, Joonsup Shim, Jinha Lim, Jaeyong Jeong, Bong Ho Kim, and SangHyeon Kim School of Electrical Engineering, KAIST</p>
TP-205	<p>Memristor-based Artificial Neuron for the Gustatory System</p> <p>Da Ye Kim¹, June Soo Kim¹, Hyunjun Kim¹, Noah Jang¹, Yujin Nam¹, Jinkyung Kim¹, Jin Park¹, Kihyun Kim¹, Seong Ho Kong¹, and Maeum Han² ¹Kyungpook National University, ²Institute of Semiconductor Fusion Technology</p>
TP-206	<p>Elastomeric Substrates for the Assembly of Freestanding 3D Mesostructures</p> <p>Yeonhee Heo, Gooyoon Chung, and Yoonseok Park Department of Advanced Materials Engineering, Kyung Hee University</p>
TP-207	<p>The DPP-DTT Thin-Film Transistor-Based Glucose Sensor with Parylene-C Gate Dielectric</p> <p>Min-Joon Kim, Dong-Jun Han, Gwang-Eun Choi, Ra-Yeong Park, and Dong-Wook Park School of Electrical and Computer Engineering, University of Seoul</p>
TP-208	<p>Minimal-Invasive, Magnetically Targetable and Controllable Neural Interfaces</p> <p>Jeongmin Yoo¹, Gyuri Shin¹, Gooyoon Chung¹, Yoonseok Park¹, Sang Hoon Park², Ji Won Lee², and Ki Jun Yu² ¹Department of Advanced Materials Engineering, Kyung Hee University, ²School of Electrical and Electronic Engineering, Yonsei University</p>



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TP-209	<p>Wide-range and selective detection of SARS-CoV-2 DNA via surface modification of electrolyte-gated IGZO thin-film transistors</p> <p>Chuljin Hwang¹, Seokhyeon Baek¹, and Sungjun Park¹, and Won-June Lee²</p> <p>¹Department of Electrical and Computer Engineering, Ajou University, ²Department of Chemistry, Purdue University</p>
TP-210	<p>A CMOS Temperature Sensor with a Reduced-Component Delta-Sigma Modulator</p> <p>조영민, 범진욱</p> <p>Department of Electronic Engineering, Sogang University</p>
TP-211	<p>Soft and Porous Wireless Hydration Sensor for Skin-Friendly Wearables</p> <p>Hyejun Kim, Seongu Kim, and Jeonghyun Kim</p> <p>Department of Electronic Convergence Engineering, Kwangwoon University</p>
TP-212	<p>Machine Learning-Based Cardiac Motion Monitoring Using Magnets and Magnetometers</p> <p>Sunjin Lee¹, Eojin Lee¹, Youn-Kyoung Baek², Ji-Hoon Kim³, and Yoonseok Park¹</p> <p>¹Kung Hee University, Department of Materials Engineering, ²KIMS, ³KIST</p>
TP-213	<p>Graphene-PEDOT:PSS Bilayer Bioelectronic Interface for Accurate Electromyography Monitoring in Wearable Sensors</p> <p>Rayoung Park, Sookyeong Kim, and Dong-Wook Park</p> <p>University of Seoul</p>
TP-214	<p>초음파의 비선형 특성을 활용한 고 대조도 이미징을 위한 콤팩트 정전 용량형 미세가공 초음파 트랜스듀서 시스템</p> <p>허근영^{1,2}, 김동훈¹, 강동현¹, 편주영¹, 이병철^{1,3,4}</p> <p>¹한국과학기술연구원, 바이오닉스 연구센터, ²고려대학교, 전기전자공학부 ³과학기술연합대학원대학교, 바이오-메디컬 융합, ⁴경희대학교, KHU-KIST 융합과학기술학과</p>
TP-215	<p>Triphenylene-Based 2D cMOFs-Metal Oxide Nanocomposite for Chemiresistive Gas Sensing at Room Temperature</p> <p>Min-Woo Kim^{1,3}, M. Jamir Ahemad¹, Jae-Hyun Lee², Byung-Joon Moon^{1,4}, and Sukang Bae^{1,4}</p> <p>¹Functional Composite Materials Research Center, KIST, ²Department of Material Science and Engineering and Department of Energy Systems Research, Ajou University, ³Department of Material Science and Engineering, Ajou University, ⁴Department of JBNU, KIST</p>



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L. Analog Design	
TP-216	<p>Design of Physically Unclonable Function Operation Circuit without Using a Reference Based on NAND Flash Structure</p> <p>Jun Hwa Jeong Tae Yeong Kim, Gyung Tae Ryu, and Ick Hyun Song Hanyang University</p>
TP-217	<p>Design Methodologies for Mass Production of Power Management Integrated Circuits (PMICs): Development Process, Design, and Reliability Verification</p> <p>Min Yong Jung KERI</p>
TP-218	<p>A 64-Gb/s 0.818-pJ/b C-PHY Transmitter Using Tri-Level Signaling</p> <p>Young-Wook Kim, Junhak Kim, Junsu Park, and Kwanso Park Yonsei University</p>
TP-219	<p>14 GHz-to-16GHz Sub-sampling LC PLL 주파수 합성기 설계</p> <p>MIN CHAN PARK, JUNG-HOON CHUN SungKyunkwan University</p>
TP-220	<p>An 8.7nW CMOS Current Reference with a Supply/Reference Current Ratio of 1.5</p> <p>MinJi Jung, Youngwoo Ji Department of Electronic Engineering, Hanbat National University</p>
TP-221	<p>Digital Electro-Optical PLL with 4GHz Laser Modulation Range</p> <p>신도현, 김종현, 범진욱 Sogang University</p>
TP-222	<p>A Novel Automatic Power Control Scheme for LiDAR Transmitter</p> <p>Yejin Choi^{1,2}, Juntong Li^{1,2}, and Sung Min Park^{1,2} ¹Division of Electronic & Semiconductor Engineering, Ewha Womans University, ²Graduate Program in Smart Factory, Ewha Womans University</p>



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TP-223	<p>FMCW LiDAR 수신부 시스템에서 입력 DC 전류를 제거하는 피드백 루프를 가진 Analog-Front-End 회로</p> <p>안예현, 이승주, 범진욱</p> <p>Department of Electronic Engineering, Sogang University</p>
TP-224	<p>A Bias Generator Based On Beta-Multiplier With Line Sensitivity Subtraction</p> <p>Kyeongmin Min, Youngwoo Ji</p> <p>Department of Electronic Engineering, Hanbat National University</p>
TP-225	<p>Push-Pull Voltage Regulator를 활용하여 Gamma Reference Voltage의 Settling Time을 줄인 OLED 소스드라이버 IC</p> <p>Won-Jo Lee, Yu-Guan Kim, Min-Woo Kim, Yun-Su Kim, Jung-Hwan Hwang, and Byung-do Yang</p> <p>School of Semiconductor Engineering, Chungbuk National University</p>
TP-226	<p>10-Bit 4-MS/s R-C Hybrid DAC Based Differential SAR ADC With Digital Error Collection Logic</p> <p>Wooseok Jung, Hyukjin Kim, and Jinwook Burm</p> <p>Sogang University</p>
TP-227	<p>High-Impedance Read-Out IC for DC Measurements Using Impedance Boosting and Noise Suppression Techniques</p> <p>Chanhyuck Kang and Jooyeol Rhee</p> <p>Department of Semiconductor Engineering, Gachon University</p>
TP-228	<p>Wide-range Multi-phase Clock Generator with Successive Clock Comparison</p> <p>Daeun Yun and Kwanso Park</p> <p>Yonsei University</p>
TP-229	<p>Zero Injection Technique for Enhancing Stability and PSR Performance in Analog LDOs</p> <p>Yunbeom Hwang and Jun-Eun Park</p> <p>Department of Electrical and Computer Engineering, Sungkyunkwan University</p>
TP-230	<p>RF 에너지 하베스팅 시스템을 위한 동적 게이트 및 바디 바이어싱을 활용한 저전압 커패시티브 DC-DC 컨버터</p> <p>Ji Won Kang and Ickjin Kwon</p> <p>Department of Electrical and Computer Engineering, Ajou University</p>



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TP-231	A 25Gb/s Wireline NRZ Transmitter with 3-Tap FFE in 28nm CMOS Jun Kyeong Cha and Kee Won Kwon Department of Semiconductor and Display Engineering, Sungkyunkwan University
TP-232	Dual-Path Output-Capacitorless LDO With Fast-Transient Response Dong-Wook Jeong and Ickjin Kwon Department of Electrical and Computer Engineering, Ajou University
TP-233	A 28-nm 0.4-1-V Capacitor-Less LDO with Low-Power High Slew-Rate Class-AB OTA Hyungmin Kang, Jeong-Min Woo, Yunho Park, and Hyunwoo Son School of Electronic Engineering, Gyeongsang National University
TP-234	Isolated Phase shifted Full bridge DC-DC Converter Jisoo Kim, Heejin Lee, Hohyun Kim, Minseok Kim, Minkwang Ji, and Joongho Choi University of Seoul
TP-235	A Modeling of High Jitter Tolerance Oversampling CDR Based on Event-Driven System Verilog Simulator Soyoung Yang ¹ , Minkyu Song ² , Seokhyeon Moon ¹ , and Jun-Eun Park ² ¹ Department of Semiconductor Convergence Engineering, Sungkyunkwan University, ² Department of Electrical and Computer Engineering, Sungkyunkwan University
R. Semiconductor Software	
TP-236	Implementation of an Improved SAN Framework to improve Backup Storage Performance Jung Kyu Park Daejin University
T. AI	
TP-237	경량 회귀 신경망 추론 시스템을 이용한 레이더 이미지 분류 구현 이준형, 김태환 한국항공대학교



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<p>TP-238</p>	<p>Probability Controllable Stochastic Neuron for Stochastic SNN Geonwoo Kum¹, Hyeyeon Jeon¹, Yoon Kim^{1,2}, and Minsuk Koo^{1,2} ¹University of Seoul, ²IM Electronics Co., Ltd.</p>
<p>TP-239</p>	<p>An ADC-Free Page Buffer-based CMOS Neuron Jinhyeok Kim¹, Minsuk Koo^{2,3}, and Yoon Kim^{1,3} ¹School of Electrical and Computer Engineering, University of Seoul, ²School of Advanced Fusion Studies and AI Semiconductor, University of Seoul, ³IM Electronics Co., Ltd.</p>
<p>TP-240</p>	<p>Adaptive Dual-Mode Processing Unit for Efficient DRAM-PIM with Partial BNN Support Seonggeun Kim^{1,2}, Jin Shin^{1,2}, and Hyun Kim^{1,2} ¹Department of Electrical and Information Engineering, Seoul National University of Science and Technology, ²Research Center for Electrical and Information Technology, Seoul National University of Science and Technology</p>
<p>TP-241</p>	<p>ViT-PatchCore: Transformer를 활용한 패치 기반 이상 탐지 신지수, 김현진 단국대학교 전자전기공학과</p>
<p>TP-242</p>	<p>An Efficient Computing Unit Integrating Floating Point and Posit for Transformer Accelerators Sungsoo Han, Dahun Choi, and Hyun Kim Department of Electrical and Information Engineering, Research Center for Electrical and Information Technology, Seoul National University of Science and Technology</p>
<p>TP-243</p>	<p>Implementation of Spiking Neural Network Characteristics in a-SZTO-Based Thin-Film Transistors for Optimized Neuromorphic Computing Applications Hyeon Dong Kim^{1,3}, Sang Ji Kim^{2,3}, Tae Ho Kim^{2,3}, Ju Young Lee^{2,3}, Seong Eun Song^{2,3}, and Sang Yeol Lee^{1,3} ¹Department of Semiconductor Engineering, Gachon University, ²Department of Electronic Engineering, Gachon University, ³Gachon Advanced Institute of Semiconductor Technology</p>



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TP-244	<p>Optimizing Hardware Footprint: A Versatile Multi-Precision Arithmetic Unit for FP and INT Operations</p> <p>Chaewon Park, Jihoon Jang, Inseong Hwang, and Hyun Kim Department of Electrical and Information Engineering, Research Center for Electrical and Information Technology, Seoul National University of Science and Technology</p>
TP-245	<p>Object Detection based on Super-Resolution Algorithms for Edge Imaging Devices</p> <p>Chan-Myeong Ryu, Tae-Hoon Eom, and Hyeon-June Kim Department of Intelligent Semiconductor, Seoul National University of Science and Technology</p>
TP-246	<p>Batch Training Optimization Method on Neuromorphic Hardware</p> <p>In-Seok Lee and Jong-Ho Lee Department of Electrical and Computer, Seoul National University</p>
TP-247	<p>Real-Time Military Wall-Penetrating Radar System Using 60-64 GHz band mmWave Radar and FPGA-Based Deep Learning Accelerator</p> <p>Jinwoo Park¹, Gimin Bae², Dongyoon Kim¹, Jaeheon Kim¹ and Janghyong Lee¹ ¹Institute of Innovation for Future Army, ²Kluge Herre</p>
TP-248	<p>Vision Transformer with Checkerboard Self-Attention</p> <p>Seungju Lee and Byung-soo Kim SoC Platform Research Center, KETI</p>
TP-249	<p>Capacitor-Based ReLU Neuron Circuit with Successive Integration and Rescaling</p> <p>Sojoong Kim¹, Minsuk Koo^{1,2}, and Yoon Kim^{1,2} ¹University of Seoul, Korea, ²IM Electronics</p>
TP-250	<p>Noise Robust Analog Matrix-Vector Multiplication Accelerator Architecture Using Capacitive Coupling Principle</p> <p>Yong Woo Kim¹, Jung Nam Kim¹, Minsuk Koo^{2,3}, and Yoon Kim^{1,3} ¹Department of Electrical and Computer Engineering, University of Seoul, ²School of Advanced Fusion Studies and AI Semiconductor, University of Seoul, ³IM Electronics</p>
TP-251	<p>Operation Methodologies and Device Specifications for Analog AI Training Accelerator with Resistive Cross-Point Arrays</p> <p>Jinho Byun, Seungkun Kim, Doyoon Kim, Jimin Lee, Wonjae Ji, and Seyoung Kim Department of Materials Science and Engineering, POSTECH</p>



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C. Material Growth & Characterization

<p>TP-252</p>	<p>Protonation-driven Polarization Retention Failure in Nano-columnar Lead-free Ferroelectric Thin Films</p> <p>Muhammad Sheeraz¹, Chang Won Ahn¹, Nguyen Xuan Duong¹, Soo-Yoon Hwang², Ji-Soo Jang³, Eun-Young Kim⁴, Yoon Ki Kim⁵, Jaeyeong Lee⁶, Jong Sung Jin⁶, Jong-Seong Bae⁶, Myang Hwan Lee⁷, Hyoung-Su Han⁸, Gi-Yeop Kim², Shinuk Cho¹, Tae Kwon Song⁷, Sang Mo Yang⁵, Sang Don Bu⁴, Seung-Hyub Baek^{3,9}, Si-Young Choi^{2,10,11}, Ill Won Kim¹, and Tae Heon Kim^{1,3}</p> <p>¹Department of Physics and Energy Harvest-Storage Research Center, University of Ulsan, ²Department of Materials Science and Engineering, POSTECH, ³Electronic Materials Research Center, KIST, ⁴Department of Physics, Research Institute of Physics and Chemistry, Jeonbuk National University, ⁵Department of Physics, Sogang University, ⁶Busan Center, KBSI, ⁷School of Materials Science and Engineering, Changwon National University, ⁸School of Materials Science and Engineering, University of Ulsan, ⁹Division of Nano & Information Technology, KIST School, University of Science and Technology, ¹⁰Center for Van der Waals Quantum Solids, Institute for Basic Science, ¹¹Department of Semiconductor Engineering, POSTECH</p>
<p>TP-253</p>	<p>Stress Effects on (Hf, Zr)O₂ Ferroelectrics Induced by Different Substrates</p> <p>Hyun Woo Jeong¹, Dong Hee Han¹, Younghwan Lee², and Min Hyuk Park¹</p> <p>¹Seoul National University, ²Chonnam National University</p>
<p>TP-254</p>	<p>Gallium Arsenide Nanowires with Embedded Quantum Dots for Single Photon Emission</p> <p>Illia Tikhonov^{1,2}, Sung-Yul L. Park¹, Ga Hyun Cho^{1,3}, Jindong Song^{1,2}</p> <p>¹KIST, ²University of Science and Technology, ³Hanyang University</p>
<p>TP-255</p>	<p>Wafer-Scale MOCVD Growth of MoS₂ Films for 2D TMDs FET Applications</p> <p>Jong Min Song^{1,2}, Dong Hyun Seo^{1,2}, Ji Won Heo¹, Jin Hoo Seong^{3,4}, and Tae Wan Kim^{1,2,5}</p> <p>¹Department of Intelligent Semiconductor Engineering, University of Seoul, ²D Epi inc., ³KRISS, ⁴Department of Semiconductor Science, Engineering and Technology, Korea Aerospace University, ⁵School of Advanced Fusion Studies, University of Seoul</p>
<p>TP-256</p>	<p>Defect Analyses of Oxide Semiconductor Materials by Photo-Induced Current Transient Spectroscopy and Artificial Intelligence 1D Convolutional Neural Networks</p> <p>Hui Gu Lee¹ and Jinpyo Hong^{1, 2}</p>



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	¹ Division of Nano-scale Semiconductor Engineering, Hanyang University, ² Department of Physics, Hanyang University
TP-257	<p>Characterization of InAs QDs Filled in Ga-Droplet Etched Nanoholes</p> <p>You Jin Lee^{1,2}, Suk In Park¹, Moritz Meinecke³, Andreas Pfenning³, Tobias Huber-Loyola³, Sven Höfling³, Peter Gschwandtner³, and Jindong Song¹</p> <p>¹Korea Institute of Science and Technology, ²KIST School at University of Science and Technology, ³Julius-Maximilians-Universität Würzburg</p>
TP-258	<p>Direct Measurement of Polarization-Electric Field Hysteresis Loops in Two-Dimensional Sliding Ferroelectrics</p> <p>June Hee Shin¹, Sae-A Kim¹, Kahyun Ko¹, Byunghyun Kim¹, Hyobin Yoo², and Sang Mo Yang¹</p> <p>¹Sogang University, ²Seoul National University</p>
TP-259	<p>Substitutional Doping for P-type MoS₂ with Liquid Phase Metal</p> <p>Dong-Yeong Kim¹, TaeJoon Mo^{1,2}, GunWoo Yoo^{1,2}, Min-Yeong Choi^{1,2}, and Cheol-Joo Kim^{1,2}</p> <p>¹Department of Chemical Engineering, POSTECH, ²Center for Van der Waals Quantum Solids, IBS</p>
TP-260	<p>Oxidized Si-terminated Diamond MOSFET with High-k Dielectric</p> <p>Yoonseok Nam¹, Taemyung Kwak¹, Geunho Yoo¹, Seong-Woo Kim², and Okhyun Nam¹</p> <p>¹Department of Nano & Semiconductor Engineering, Tech University of Korea, ²Orbray Co., Ltd.</p>
TP-261	<p>Control of Polarization Switching Dynamics in Ferroelectric Hf_{0.7}Zr_{0.3}O₂ Thin Films by Using Oxygen Scavenging Effect</p> <p>Sang Won An, June Hee Shin, and Sang Mo Yang</p> <p>Department of Physics, Sogang University</p>
TP-262	<p>Promoter Effects in Crystal Growth of MoS₂ Monolayer Films synthesized by Atomic Layer Deposition</p> <p>Su Jin Kim and Hyun Seok Lee</p> <p>Department of Physics, Chungbuk National University</p>
TP-263	<p>NOBF₄ Treatment Effects of Optical Properties in CVD-grown MoS₂ Monolayers</p> <p>Tae Yeon Kim and Hyun Seok Lee</p> <p>Department of Physics, Chungbuk National University</p>



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<p>TP-264</p>	<p>Tellurium Based p-Type Material Growth for Electronic Device Min Soo Moon², Gang Hee Han², Ju Hwan Baek³, Jin Young Park^{1,3}, Yonas Tsegaye Megra^{1,3}, Hoon Hahn Yoon^{1,3}, Hyeon-Jin Shin^{1,3}, and Dong-Ho Kang^{1,3} ¹Department of Semiconductor Engineering, GIST, ²Department of Physics, Incheon National University, ³School of Electrical Engineering and Computer Science, GIST</p>
<p>TP-265</p>	<p>Comparative Analysis of Electrical and Morphological Properties of ZnSnN2 Films Deposited by RF Sputtering on GaAs, Sapphire, and GaN Substrates Ju Chan Hwang¹, and Kwang Wook Park^{1,2} ¹Division of Electronics and Information Engineering, Jeonbuk National University, ²Division of Advanced Materials Engineering, Jeonbuk National University</p>
<p>TP-266</p>	<p>Nitridation Effects in Strong Photoluminescence Enhancement for Monolayers and Stacked Bilayers of MoS₂ Min Choi, Han Dong Lee, and Hyun Seok Lee Department of Physics, Chungbuk National University</p>
<p>TP-267</p>	<p>Understanding Growth Mechanism of MOCVD-grown MoS₂ on SiO₂ under BEOL Compatible Temperature Minsu Jeon¹, Wonjae Choi¹, Jihun Mun¹, Taehyeon Kim^{1,2}, Jaemin Myoung^{1,2}, Taesung Kim², and Jong Moon Ha³ ¹Korea Research Institute of Standards and Science, ²Sungkyunkwan University, ³Ajou University</p>
<p>TP-268</p>	<p>Strong SWIR Photoluminescence of MOCVD Grown (In)GaAs/Ge/(In)GaAs Minseong Seo¹, Wook Kim¹, Sujong Kim¹, Younghan Yook¹, Doyoung Yuk¹, Haoyan Rong¹, and Jaejin Lee^{1,2}, and Sunghyun Moon² ¹Department of Intelligence Semiconductor Engineering, Ajou University, ²Department of Electrical and Computer Engineering, Ajou University</p>
<p>TP-269</p>	<p>Manipulation of P-Type Doping and Reduced Charge Trapping in MoS₂ Monolayers via Mild N₂ Plasma Treatment Su Jin Kim, Min Choi, and Hyun Seok Lee Department of Physics, Chungbuk National University</p>
<p>TP-270</p>	<p>Analysis of Crystalline Phase Transformation in Ga₂O₃ Thin Films Grown on GaN Templates by MOCVD Dong Ho Lee, Seon Jin Mun, Si Gwang Kim, Jun Ha Park, Hyung Soo Ahn, and Min yang Department of Nano-Semiconductor Engineering, National Korea Maritime and Ocean University</p>



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TP-271	<p>Electromagnetic Interference Shielding with Oxidation- and Water-resistant Functionalized MXene films</p> <p>Jaeun Park¹, Shi-Hyun Seok¹, Yujin Chae¹, Yeoseon Sim¹, Hyeonwoo Lee¹, Haeng Un Yeo¹, Soon-Yong Kwon¹, Young Ho Jin¹, Ju-Hyoung Han¹, Mincheal Kim², EunMi Choi², Sangjin Seo³, Taesung Kim³, and Sung Hyun Park⁴</p> <p>¹Department of Materials Science and Engineering and Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ²Department of Electrical Engineering, UNIST, ³Department of Mechanical Engineering, UNIST, ⁴Sustainable Technology and Wellness R&D Group, KITECH</p>
TP-272	<p>Simultaneous synthetic metallization for constructing pure edge-contact metal-semiconductor junction transistor arrays</p> <p>Sora Jang¹, Juwon Han¹, Changwook Jeong¹, Soon-Yong Kwon¹, Seunguk Song^{1,2}, Aram Yoon^{1,3}, and Zonghoon Lee^{1,3}</p> <p>¹Department of Materials Science and Engineering & Graduate School of Semiconductor Materials and Devices Engineering, UNIST, ²Department of Energy Science & Department of Energy, Sungkyunkwan University, ³CMCM, IBS</p>
TP-273	<p>Effect of Top Electrode Materials on Polarization Switching in Post-deposition Annealed Hf_{0.5}Zr_{0.5}O₂ Capacitors</p> <p>Yu Bin Park¹, Tae Hyun Jung¹, Jung Kyu Lee¹, Beomjun Kim¹, Sang Mo Yang¹, and Hyobin Yoo²</p> <p>¹Sognag University, ²Seoul National University</p>
TP-274	<p>높은 비표면적을 가지는 TiO₂ 나노 구조체 합성 최적화 및 특성 평가</p> <p>Inhee Cho¹, Jai Chan Lee², Seong Hyeon Kim^{1,2}, Hyeon Sik Kim^{1,3}, and Han Young Yang^{1,4}</p> <p>¹KORAM, Korea Institute of Industrial Technology, ²School of Materials science and engineering Sungkyunkwan University, ³School of Electrical Engineering, Kookmin University, ⁴School of Chemical and Biological Engineering, Korea University</p>
TP-275	<p>Synthesis of Ti₄N₃T_x MXene Using Diverse Fluoride Salts-assisted Etching Solution</p> <p>Yujin Chae¹, Jaeun Park¹, Shi-Hyun Seok¹, Yeoseon Sim¹, Ju-Hyoung Han¹, Young Ho Jin¹, and Soon-Yong Kwon^{1,2}</p> <p>¹Department of Materials Science and Engineering, UNIST, ²Graduate School of Semiconductor Materials and Devices Engineering, UNIST</p>



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<p>TP-276</p>	<p>Correlation between Phase Transition Behavior and Growth Parameters of Sputtered Vanadium Dioxide Thin Films Hyesoo Jin and Donghee Park Center for Quantum Technology, Post-Silicon Semiconductor Institute, KIST</p>
<p>TP-277</p>	<p>Precise Measurements of Polarization States and Piezoelectric Coefficient in Sliding Ferroelectrics Saea Kim, June Hee Shin, Tae Hyun Jung, and Sang Mo Yang Department of Physics, Sogang University</p>
<p>TP-278</p>	<p>Harmonic Measurement Methods for Evaluation of Spin-orbit Torque Efficiency Hongwon Jeon¹, Woojin Kim¹, Seongjong Yoon¹, Soogil Lee^{1,2}, Gunwoo Jung^{1,3}, Heungrae Cho^{1,3}, and Daeun Woo^{1,4} ¹Department of Semiconductor Engineering, Gachon University, ²Department of Electronic Engineering, Gachon University, ³Department of Electrical Engineering, Gachon University, ⁴Department of Physics, Gachon University</p>
<p>TP-279</p>	<p>Growth of cation-controlled epitaxial nickelate thin films by co-sputtering Changhwan Kim¹, Min Young Jung¹, Kyeong Jun Lee¹, Seo Hyoung Chang¹, Yeong Gwang Khim², Young Jun Chang², and Ji-Hwan Kwon³ ¹Department of Physics, Chung-Ang University, ²Department of Physics, University of Seoul, ³KRISS</p>
<p>TP-280</p>	<p>Heteroepitaxial Growth of Single Crystal (111) Diamond on Al₂O₃ Substrate Seolyoung Oh, Taemyung Kwak, Yeonghwa Kwon, Yoonseok Nam, Eonhee Roh, Geunho Yoo, and Okhyun Nam CANS, Department of Nano-Semiconductor Engineering, Tech university of Korea</p>
<p>TP-281</p>	<p>Boron-doped Diamond Metal Semiconductor Field Effect Transistor Using Selectively Grown P+ Layer Eonhee Roh¹, Taemyung Kwak¹, Seolyoung Oh¹, Yeonghwa Kwon¹, Yoonseok Nam¹, Geunho Yoo¹, Seongwoo Kim², and Okhyun Nam¹ ¹CANS, Department of Nano-Semiconductor Engineering, Tech university of Korea (TU-Korea), Korea, ²Orbray Company</p>
<p>TP-282</p>	<p>Thickness Dependent Structural Evolution in Epitaxial CaZrO₃ Thin Films Dong-Hun Han^{1, 2}, Ho-Won Jang², Tae-Heon Kim¹, and Seung-Hyub Baek ¹Electronic Materials Research Center, KIST, ²Department of Materials Science and Engineering, Research Institute of Advanced Materials, Seoul National University</p>



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<p>TP-283</p>	<p>Heteroepitaxial Diamond Grown on Compliant Substrate Using SOI Air-void Structure Yeonghwa Kwon, Taemyung Kwak, Geunho Yoo, and Okhyun Nam Department of Nano & Semiconductor Engineering, Tech University of Korea</p>
<p>TP-284</p>	<p>VO₂(B)/V₂O₅ Nanocomposite Thermistor for Enhanced High-Temperature Performance in Microbolometers Jeongeun Mo^{1,2}, Donghee Park¹, Jeong Min Baik², and Won Jun Choi¹ ¹Center for Quantum Technology, KIST, ²School of Advanced Materials Science and Engineering, Sungkyunkwan University</p>
<p>TP-285</p>	<p>Epitaxial Growth, Bandgap, and Work function of 1T-HfSe₂ Thin Films Min Cheol Kim¹, Tae Gyu Rhee^{1,2}, Young Rok Khim¹, Young hoon Khim¹, Dang Nguyen Hoang³, Nguyen Huu Lam³, Ganbat Duvjir³, Hyuk Jin Kim¹, Jungdae Kim³, Young Jun Chang¹ ¹University of Seoul, ²KIST, ³University of Ulsan</p>
<p>TP-286</p>	<p>Thermal Conductivity Measurements of h-BN Thin Films Taeyeon Kim¹, Sungsan Kang², Minkyu Je¹, Jihyun Kim¹, Sangyeon Pak², and Jungwan Cho¹ ¹Sungkyunkwan University, ²Hongik University</p>
<p>TP-287</p>	<p>Dielectric and lattice dynamics of ultra-wide bandgap BaZrO₃ Yoon Seok Oh¹, Syed Bilal Junaid², Furqanul Hassan Naqvi², Joon Woo Lee¹, Hei Woong Lee¹, Byeong-Gwan Cho³, Tae-Yeong Koo³, Dirk Wulferding⁴, and Jae-Hyeon Ko² ¹UNIST, ²Hallym University, ³Pohang Accelerator Laboratory, ⁴Seoul National University</p>
<p>TP-288</p>	<p>Thermal Conductivity Measurements of Thin Metal Alloy Films Minkyu Je, Ajin Jo, Taeyeon Kim, Chan Kim, Jihyun Kim, Dongwoo Lee, and Jungwan Cho Sungkyunkwan University</p>
<p>TP-289</p>	<p>Efficient Photocurrent Generation in 50 nm Thin Sn Halide Perovskite by Overlapping Absorption with Fabry-Perot Resonances Jia Choi^{1,2}, Donggyu Lim³, Hansol Park^{1,2}, Kyu-Tae Lee³, and Hui Joon Park^{1,2,4} ¹Department of Organic and Nano Engineering, Hanyang University, ²Human-Tech Convergence Program, Hanyang University, ³Department of Physics, Inha University, ⁴Department of Semiconductor Engineering, Hanyang University</p>



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TP-290	<p>2D Copper@Carbon Core-Shell Nanosheets for Electromagnetic Interference Shielding</p> <p>Jaewon Yeom^{1,2}, Byung Joon Moon^{1,2}, Tae-Wook Kim^{2,3}, and Sukang Bae^{1,2}</p> <p>¹Functional Composite Materials Research Center, KIST, ²Department of JBNU-KIST Industry-Academia Convergence Research, Jeonbuk National University, ³Department of Flexible and Printable Electronics, Jeonbuk National University</p>
<p>V. Quantum Technology</p>	
TP-291	<p>Silicon Switching Devices Utilizing Positive Feedback Loops for Cryogenic Quantum Computer</p> <p>Hakin Kim and Doohyeok Lim</p> <p>Kyonggi University</p>
TP-292	<p>Atom-cavity System for Deterministic Single Photon Generation</p> <p>Uijin Kim, Dowon Lee, Donggeon Kim, Taegyul Ha, Eunchul Jeong, and Moonjoo Lee</p> <p>Department of Electrical Engineering, POSTECH</p>
TP-293	<p>Observation of more than 60 trapped ions in a linear Paul trap</p> <p>Youngil Moon, Jongcheol Won, Sangsoo Han, and Moonjoo Lee</p> <p>Department of Electrical Engineering, POSTECH</p>
TP-294	<p>Controlled Loading Slot Structure Fabrication Using SOI Wafers for Enhanced Performance in Ion Trap Chips</p> <p>Chiyoon Kim^{1,2,3}, KwangYeul Choi^{1,2,3}, Seungwoo Yoo^{1,2,3}, Suhan Kim^{1,2,3} Eui-Hwan Chung,^{2,3} and Taehyun Kim^{1,2,3}</p> <p>¹Department of Computer Science and Engineering, Seoul National University, ²Automation and System Research Institute, Seoul National University, ³ISRC, Inter-university Semiconductor Research Center</p>
TP-295	<p>Fabricating an Ion Trap Chip with Segmented Island Electrodes using the Dual Damascene Process</p> <p>Suhan Kim^{1,2,3}, KwangYeul Choi^{1,2,3}, Seungwoo Yoo^{1,2,3}, Chiyoon Kim^{1,2,3}, Eui-Hwan Chung,^{2,3} and Taehyun Kim^{1,2,3}</p> <p>¹Department of Computer Science and Engineering, Seoul National University, ²Automation and System Research Institute, Seoul National University, ³ISRC, Inter-university Semiconductor Research Center</p>
TP-296	<p>Tip-Enhanced Single-Photon Emission from hBN Defects</p> <p>Hyeonmin Oh¹, Taeyoung Moon¹, Hyeongwoo Lee¹, and Kyoung-Duck Park¹</p> <p>POSTECH</p>



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TP-297	<p>An Experimental Setting for Individual Addressing of 5 Ions Using Fully Controlled 2 Axis AOD</p> <p>Yongha Shin, Keumhyun Kim, Hyegoo Lee, Youngil Moon, Sangsoo Han, Junhee Cho, Myunghun Kim¹, and Moonjoo Lee Department of Electrical Engineering, POSTECH</p>
TP-298	<p>Trapping and Manipulation of ⁸⁷Rb Neutral Atom Arrays Using Optical Tweezers</p> <p>Taegyul Ha, Eunchul Jeong, Dowon Lee, Donggeon Kim, Uijin Kim, and Min Jeong Lee Department of Electrical Engineering, POSTECH</p>
TP-299	<p>Spin-Spin Entanglement and Quantum State Tomography for Continuous-variable Quantum States</p> <p>Keumhyun Kim, Hyegoo Lee, Yongha Shin, Youngil Moon, Sangsoo Han, Junhee Cho, Myunghun Kim, and Moonjoo Lee Department of Electrical Engineering, POSTECH</p>